

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

**In re Application of:** Janice Nickel

**Docket No.:** 10991744-4

**Serial No. :** Not Assigned

**Group Art Unit:** Not Assigned

**Filed:** Not Assigned

**Examiner:** Not Assigned

**Title: MRAM Device Including Spin Dependent Tunneling Junction Memory Cells  
{As Amended herein}**

**A Divisional of:** Janice Nickel

**Docket No.:** 10991744-1

**Serial No. :** 09/514,934

**Group Art Unit:** 2823

**Filed:** 02/08/2000

**Examiner:** Neal Berezny

**Title: Method of Fabricating an MRAM Device Including Spin Dependent  
Tunneling Junction Memory Cells**

**PRELIMINARY AMENDMENT AND RESPONSE UNDER 37 C.F.R. §1.115**

Assistant Commissioner for Patents  
Washington, DC 20231

Sir:

Please consider this Divisional Application in light of the following preliminary amendments and remarks.

Please amend the above application as follows: